





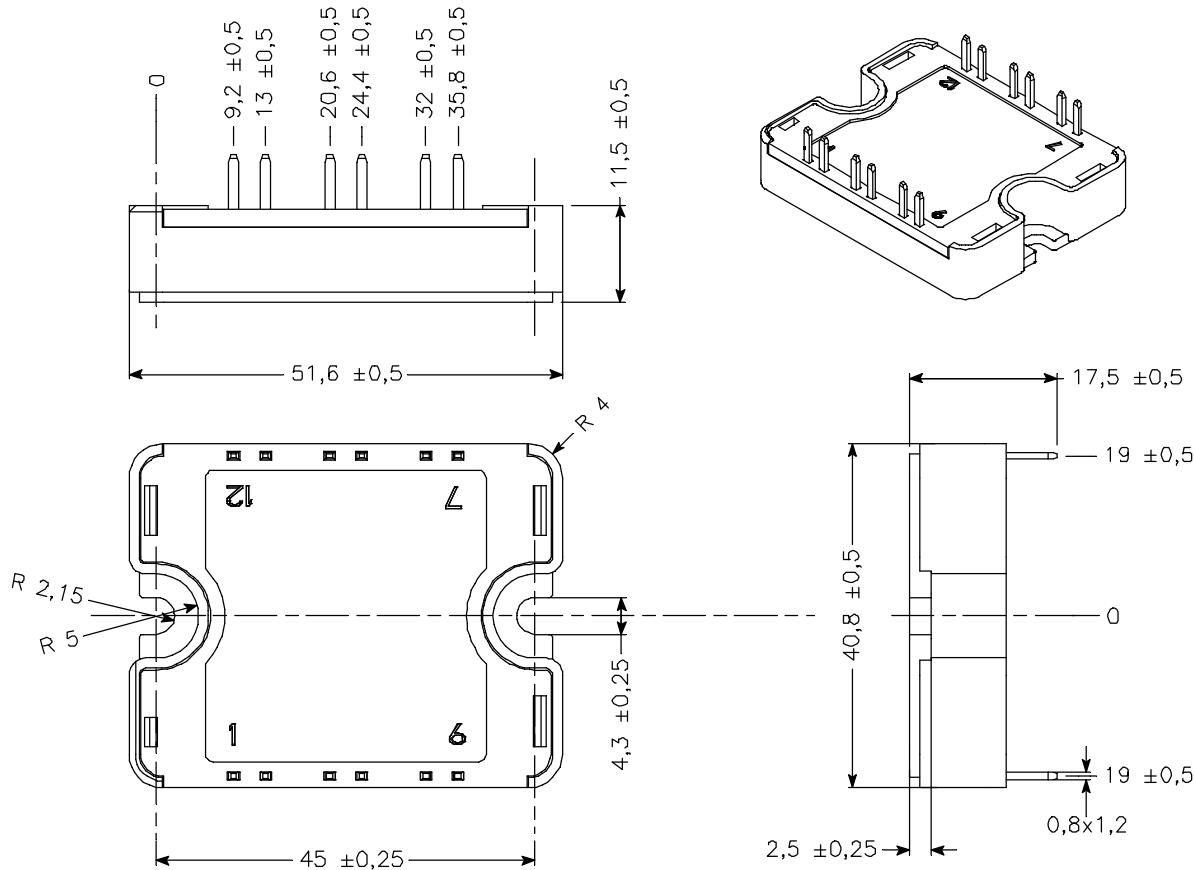
**Thermal and package characteristics**

Symbol	Characteristic		Min	Typ	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance				0.32	°C/W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t = 1 min, I <sub>isol</sub> <1mA, 50/60Hz		2500			V
T <sub>J</sub>	Operating junction temperature range		-40		150	
T <sub>STG</sub>	Storage Temperature Range		-40		125	°C
T <sub>C</sub>	Operating Case Temperature		-40		100	
Torque	Mounting torque	To heatsink	M4	2.5	4.7	N.m
Wt	Package Weight				80	g

**Temperature sensor NTC** (see application note APT0406 on www.microsemi.com for more information).

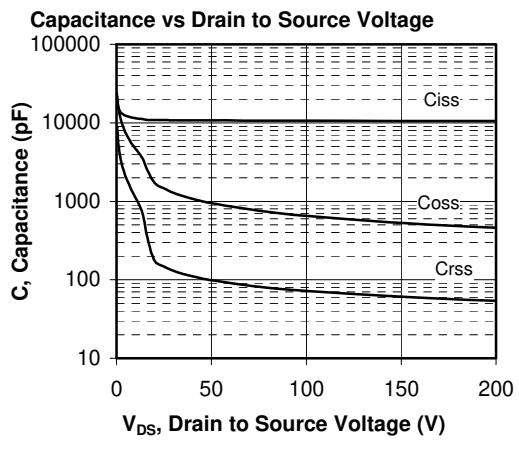
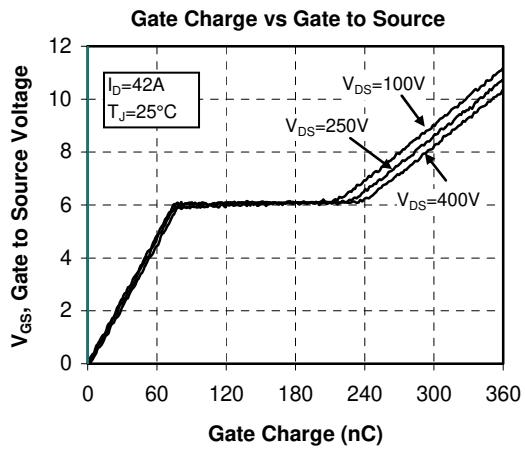
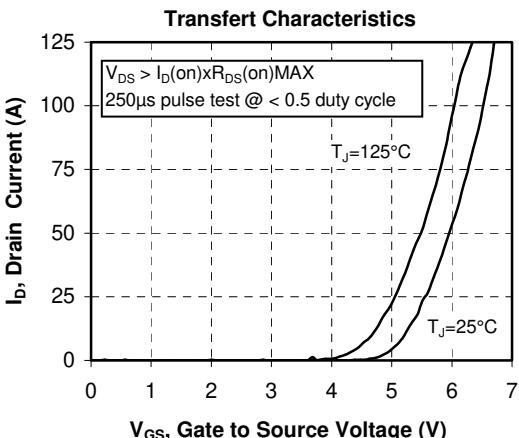
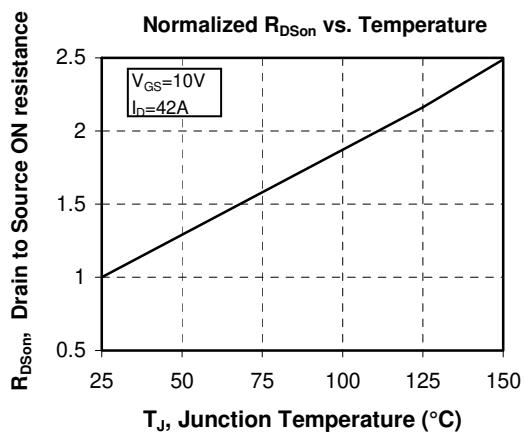
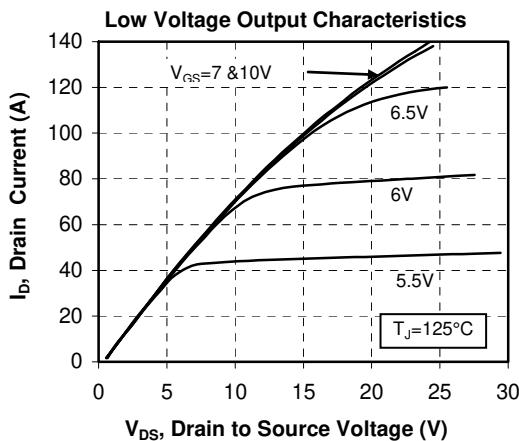
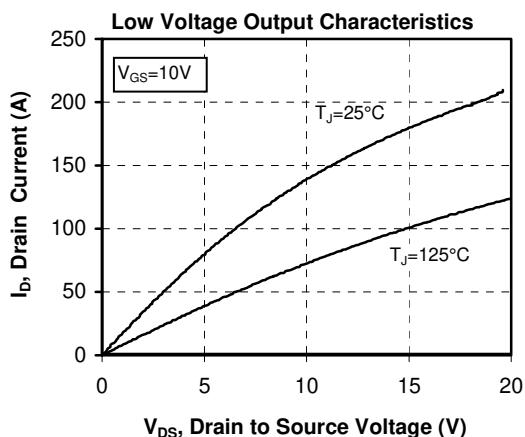
Symbol	Characteristic		Min	Typ	Max	Unit
R <sub>25</sub>	Resistance @ 25°C			50		kΩ
B <sub>25/85</sub>	T <sub>25</sub> = 298.15 K			3952		K

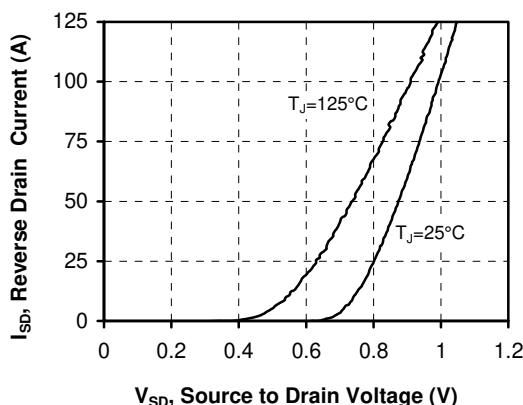
$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]} \quad \begin{aligned} T: & \text{ Thermistor temperature} \\ R_T: & \text{ Thermistor value at } T \end{aligned}$$

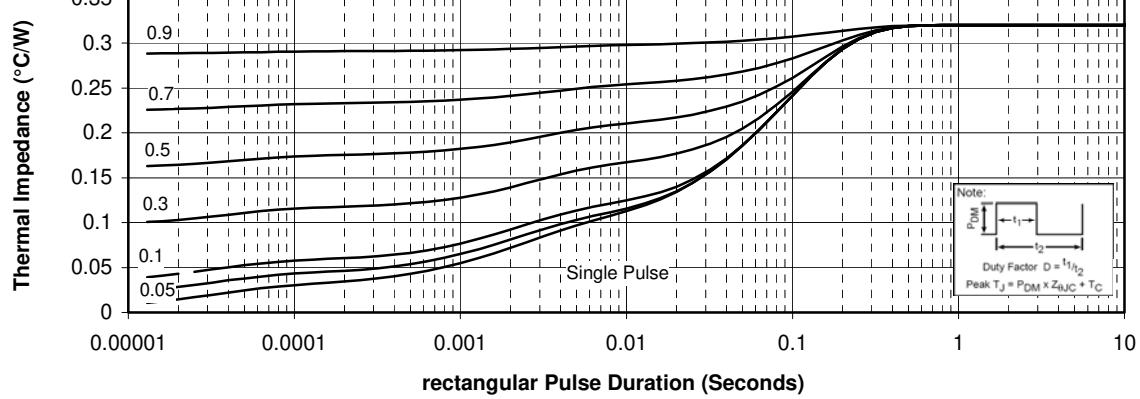
**SP1 Package outline** (dimensions in mm)


See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

### Typical Performance Curve



**Drain Current vs Source to Drain Voltage**

 $V_{SD}$ , Source to Drain Voltage (V)

**Maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration**


Microsemi reserves the right to change, without notice, the specifications and information contained herein

Microsemi's products are covered by one or more of U.S patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. U.S and Foreign patents pending. All Rights Reserved.